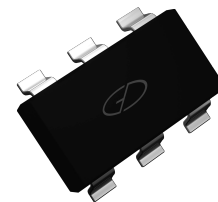


Features

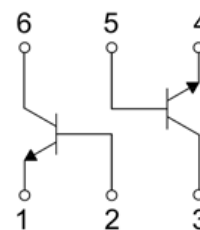
- Dual NPN transistors in one single package
- Ideal for general purpose amplifier applications

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	50	V
Collector-Emitter Voltage	V_{CE0}	45	
Emitter-Base Voltage	V_{EB0}	6	
Collector Current-Continuous	I_C	F00	mA
Power Dissipation	P_D	200	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Junction Temperature	T_R	150	$^\circ\text{C}$
Storage Temperature Range	T_{UV0}	-55 to +150	



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Schematic Diagram

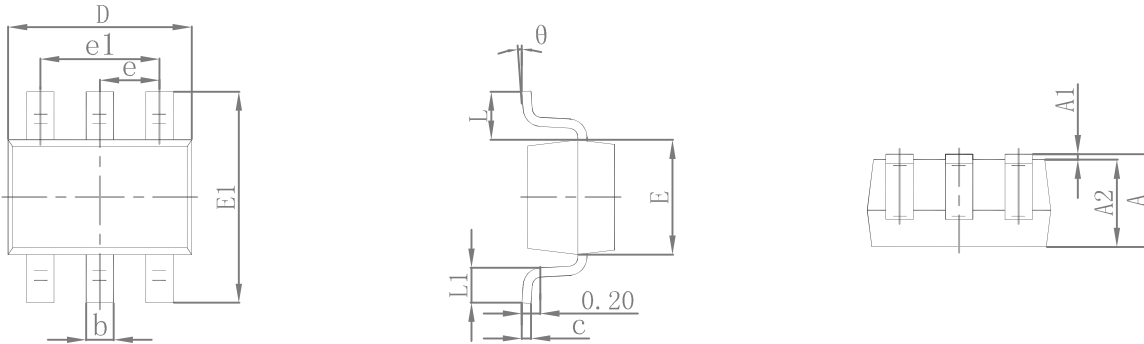
Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CB0}$	$I_C=10\mu\text{A}, I_E=0$	50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CE0}$	$I_C=1\text{mA}, I_B=0$	45	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EB0}$	$I_E=10\mu\text{A}, I_C=0$	6	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$	-	-	15	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0$	-	-	15	
DC Current Gain ¹	h_{FE}	$V_{CE}=5\text{V}, I_C=2\text{mA}$	110	-	630	
Collector-Emitter Saturation Voltage	$V_{CE(sat)(1)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$	-	-	0.25	V
	$V_{CE(sat)(2)}$	$I_C=100\text{mA}, I_B=5\text{mA}$	-	-	0.65	V
Base-Emitter Voltage	$V_{BE(1)}$	$V_{CE}=5\text{V}, I_C=2\text{mA}$	0.58	-	0.7	V
	$V_{BE(2)}$	$V_{CE}=5\text{V}, I_C=10\text{mA}$	-	-	0.77	V
Transition Frequency	f_T	$V_{CE}=5\text{V}, I_C=20\text{mA}, f=100\text{MHz}$	-	200	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$	-	2	-	pF

Note 1: Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycles $\leq 2.0\%$.

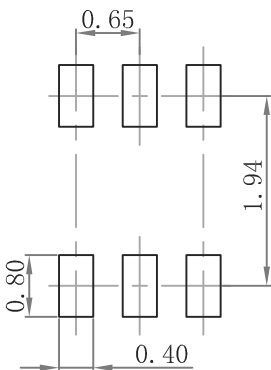
Package Outline Dimensions

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Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.100	0.150	0.004	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.400	0.085	0.094
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.